L Number	Hits	Search Text	DB	Time stamp
1	197238	light near emitting near (device or diode or element)	USPAT; US-PGPUB;	2004/09/30 15:33
			EPO; JPO;	
			DERWENT; IBM_TDB	
2	12329	(electrostatic near discharge near protect\$3) or ESD	USPAT;	2004/09/30 15:34
			US-PGPUB; EPO; JPO;	
			DERWENT;	
3	2533	(light near emitting near (device or diode or element)) and	IBM_TDB USPAT;	2004/09/30 15:34
		(lead near frame)	US-PGPUB; EPO; JPO;	
			DERWENT;	
4	15	((electrostatic near discharge near protect\$3) or ESD) and	IBM_TDB USPAT;	2004/09/30 15:34
	10	((light near emitting near (device or diode or element)) and	US-PGPUB;	2004/09/50 15:54
		(lead near frame))	EPO; JPO; DERWENT;	
_			IBM_TDB	
5	448	(light near emitting near (device or diode or element)) and ((electrostatic near discharge near protect\$3) or ESD)	USPAT; US-PGPUB;	2004/09/30 15:35
		, , , , , , , , , , , , , , , , , , , ,	EPO; JPO;	<u></u>
			DERWENT; IBM TDB	
6	75	((light near emitting near (device or diode or element)) and	USPAT;	2004/09/30 15:35
		((electrostatic near discharge near protect\$3) or ESD)) and cathode and anode	US-PGPUB; EPO; JPO;	
			DERWENT; IBM TDB	